

## US108S/N

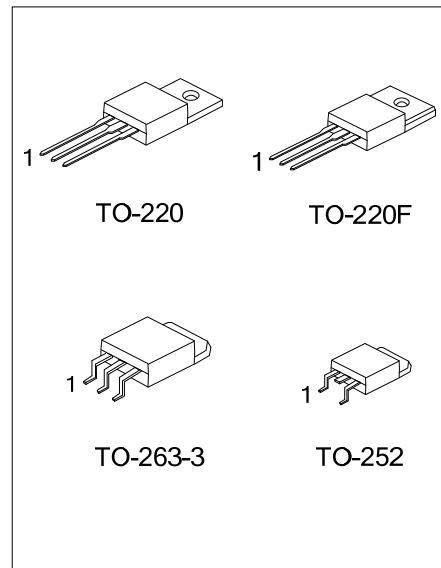
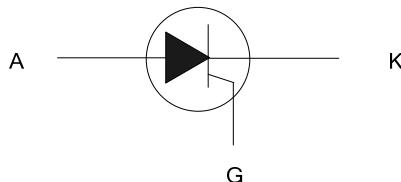
SCR

## SCRS

## ■ DESCRIPTION

The UTC **US108S/N** is suitable to fit all modes of control, found in applications such as overvoltage crowbar protection, motor control circuits in power tools and kitchen aids, inrush current limiting circuits, capacitive discharge ignition and voltage regulation circuits.

## ■ SYMBOL



## ■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
US108SL-x-TA3-T	US108SG-x-TA3-T	TO-220	K	A	G	Tube
US108SL-x-TF3-T	US108SG-x-TF3-T	TO-220F	K	A	G	Tube
US108SL-x-TN3-R	US108SG-x-TN3-R	TO-252	K	A	G	Tape Reel
US108SL-x-TQ3-T	US108SG-x-TQ3-T	TO-263-3	K	A	G	Tube
US108SL-x-TQ3-R	US108SG-x-TQ3-R	TO-263-3	K	A	G	Tape Reel
US108NL-x-TA3-T	US108NG-x-TA3-T	TO-220	K	A	G	Tube
US108NL-x-TF3-T	US108NG-x-TF3-T	TO-220F	K	A	G	Tube
US108NL-x-TN3-R	US108NG-x-TN3-R	TO-252	K	A	G	Tape Reel
US108NL-x-TQ3-T	US108NG-x-TQ3-T	TO-263-3	K	A	G	Tube
US108NL-x-TQ3-R	US108NG-x-TQ3-R	TO-263-3	K	A	G	Tape Reel

Note: Pin Assignment: K: Cathode A: Anode G: Gate

 (1) Packing Type (2) Package Type (3) Peak Voltage (4) Lead Free	(1) T: Tube, R: Tape Reel (2) TA3: TO-220, TF3: TO-220F, TN3: TO-252, TQ3: TO-263-3 (3) 4: 400V, 6: 600V, 8: 800V (4) L: Lead Free, G: Halogen Free
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## ■ MARKING INFORMATION

PACKAGE	MARKING	
	US108S	US108N
TO-220 TO-220F TO-252 TO-263-3	 Lot Code ← 1 → Data Code	 Lot Code ← 1 → Data Code

■ ABSOLUTE MAXIMUM RATING

PARAMETER		SYMBOL	RATING	UNIT
Repetitive Peak Off-State Voltages	US108S/N-4	$V_{DRM}$ $V_{RRM}$	400	V
	US108S/N-6		600	
	US108S/N-8		800	
RMS On-State Current (180°Conduction Angle) ( $T_C = 110^\circ C$ )		$I_{T(RMS)}$	8	A
Average On-State Current (180°Conduction Angle) ( $T_C = 110^\circ C$ )		$I_{T(AV)}$	5	A
Non Repetitive Surge Peak On-State Current ( $T_J = 25^\circ C$ )	$t_P=8.3ms$	US108S	73	A
		US108N	73	
	$t_P=10ms$	US108S	70	
		US108N	70	
$I^2t$ Value For Fusing ( $t_P = 10 ms$ , $T_J = 25^\circ C$ )		$I^2t$	24.5 45	A <sup>2</sup> S
Critical Rate Of Rise Of On-State Current ( $I_G = 2 \times I_{GT}$ , $t_R \leq 100 ns$ , $T_J = 125^\circ C$ , $F = 60Hz$ )		$dI/dt$	50	A/ $\mu$ s
Peak Gate Current ( $t_P=20\mu s$ , $T_J = 125^\circ C$ )		$I_{GM}$	4	A
Peak Reverse Gate Voltage	US108N	$V_{RGM}$	5	V
Average Gate Power Dissipation ( $T_J= 125^\circ C$ )		$P_{G(AV)}$	1	W
Junction Temperature		$T_J$	-40 ~ +125	°C
Storage Temperature		$T_{STG}$	-40 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS		UNIT	
Junction to Ambient	TO-220/TO-220F	$\theta_{JA}$	60		K/W	
	TO-263-3		110			
	TO-252		2.0		K/W	
Junction to Case	TO-220/TO-263-3	$\theta_{JC}$	4.0			
	TO-252		2.0			

■ ELECTRICAL CHARACTERISTICS ( $T_J=25^\circ C$ , unless otherwise specified)

**US108S(SENSITIVE)**

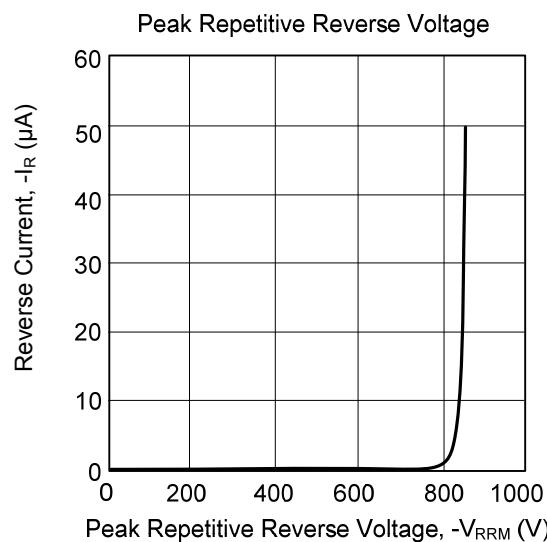
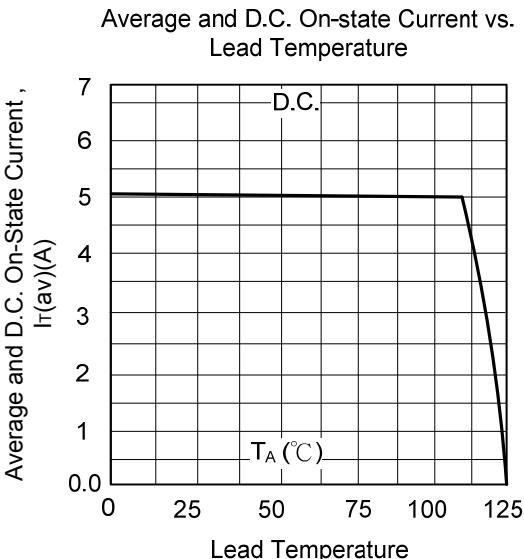
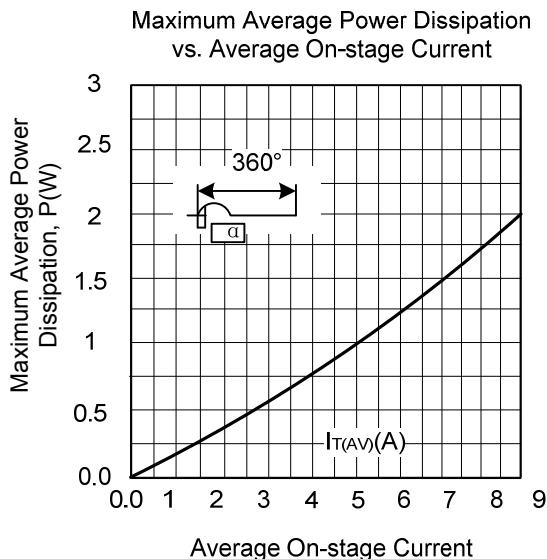
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Gate Trigger Current	$I_{GT}$	$V_D = 12 V$ , $R_L = 140\Omega$			200	$\mu A$
Gate Trigger Voltage	$V_{GT}$	$V_D = 12 V$ , $R_L = 140\Omega$			0.8	V
Gate Non-Trigger Voltage	$V_{GD}$	$V_D = V_{DRM}$ , $R_L = 3.3k\Omega$ $R_{GK} = 220$ $T_J = 125^\circ C$	0.1			V
Reverse Gate Voltage	$V_{RG}$	$I_{RG} = 10 \mu A$	8			V
Holding Current	$I_H$	$I_T = 50mA$ , $R_{GK} = 1k\Omega$			5	mA
Latching Current	$I_L$	$I_G = 1mA$ , $R_{GK} = 1k\Omega$			6	mA
Circuit Rate Of Change Of off-State Voltage	$dV/dt$	$V_D = 65 \% V_{DRM}$ , $R_{GK} = 220\Omega$	5			V/ $\mu$ s
On-State Voltage	$V_{TM}$	$I_{TM} = 16A$ , $t_P = 380 \mu s$			1.6	V
Threshold Voltage	$V_{T0}$	$T_J = 125^\circ C$			0.85	V
Dynamic Resistance	$R_D$	$T_J = 125^\circ C$			46	$m\Omega$
Off-State Leakage Current	$I_{DRM}$	$V_{DRM} = V_{RRM}$ , $R_{GK} = 220\Omega$			5	$\mu A$
	$I_{RRM}$	$V_{DRM} = V_{RRM}$ , $R_{GK} = 220\Omega$			1	mA

## ■ ELECTRICAL CHARACTERISTICS(Cont.)

## US108N(SENSITIVE)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Gate Trigger Current	$I_{GT}$	$V_D = 12V, R_L = 33\Omega$	2		15	mA
Gate Trigger Voltage	$V_{GT}$	$V_D = 12V, R_L = 33\Omega$			1.3	V
Gate Non-Trigger Voltage	$V_{GD}$	$V_D = V_{DRM}, R_L = 3.3 k\Omega$	0.2			V
Holding Current	$I_H$	$I_T = 100mA$ Gate open			30	mA
Latching Current	$I_L$	$I_G = 1.2 I_{GT}$			70	mA
Circuit Rate Of Change Of off-State Voltage	$dV/dt$	$V_D = 67 \% V_{DRM}$ Gate open	150			V/ $\mu$ s
On-State Voltage	$V_{TM}$	$I_{TM} = 16 A, t_P = 380 \mu s$			1.6	V
Threshold Voltage	$V_{t0}$	$T_J = 125^\circ C$			0.85	V
Dynamic Resistance	$R_D$	$T_J = 125^\circ C$			16	m $\Omega$
Off-State Leakage Current	$I_{DRM}$ $I_{RRM}$	$V_{DRM} = V_{RRM}$			5 2	$\mu$ A mA

■ TYPICAL CHARACTERISTICS



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